

P24LF4QMK

Power MOSFETs

40V, 24A, N-channel

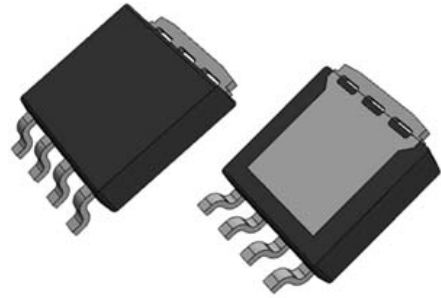
Feature

- N-channel
- Small SMD
- Low Ron
- Low Vth
- Low Capacitance
- Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

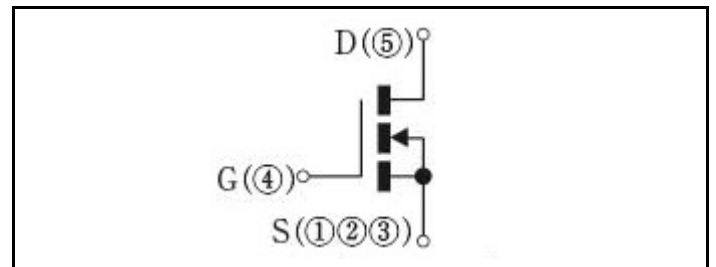
OUTLINE

Package (House Name): LF

Package (JEDEC Code): MO-235B similar



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 175	°C
Channel temperature	Tch		-55 to 175	°C
Drain-source voltage	V _{DSS}		40	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		24	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, duty=1/100	72	A
Total power dissipation	P _T		50	W
Single avalanche current	I _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	13	A
Single avalanche energy	E _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	19	mJ

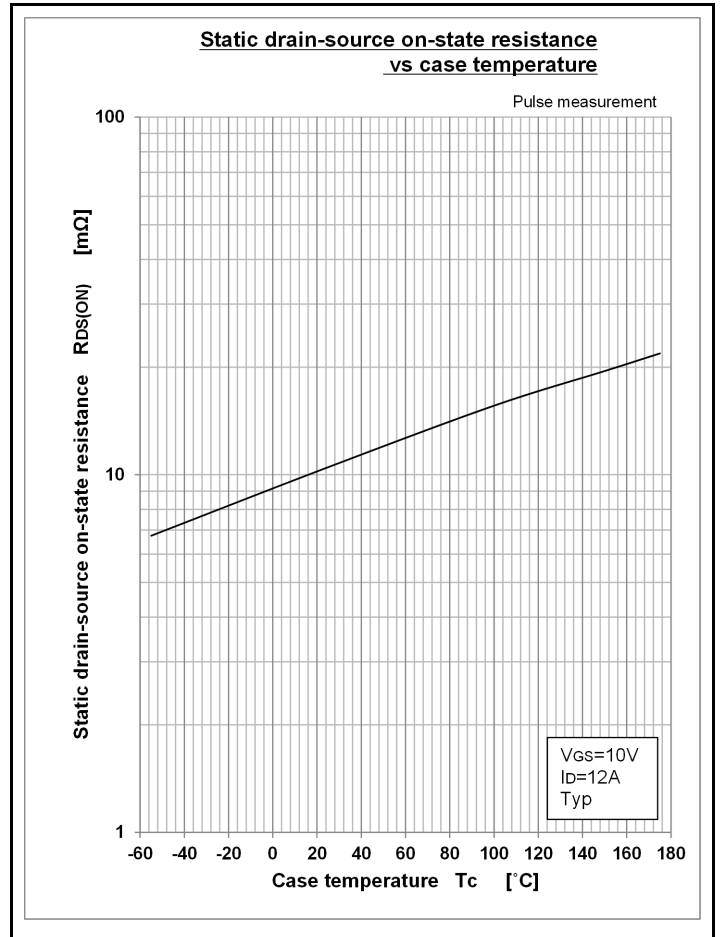
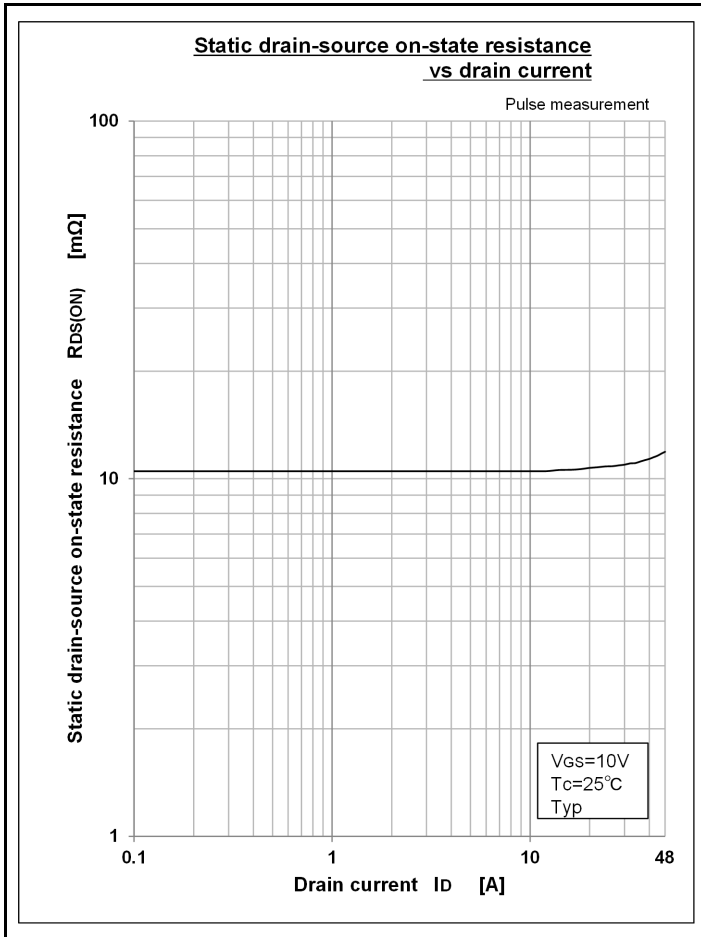
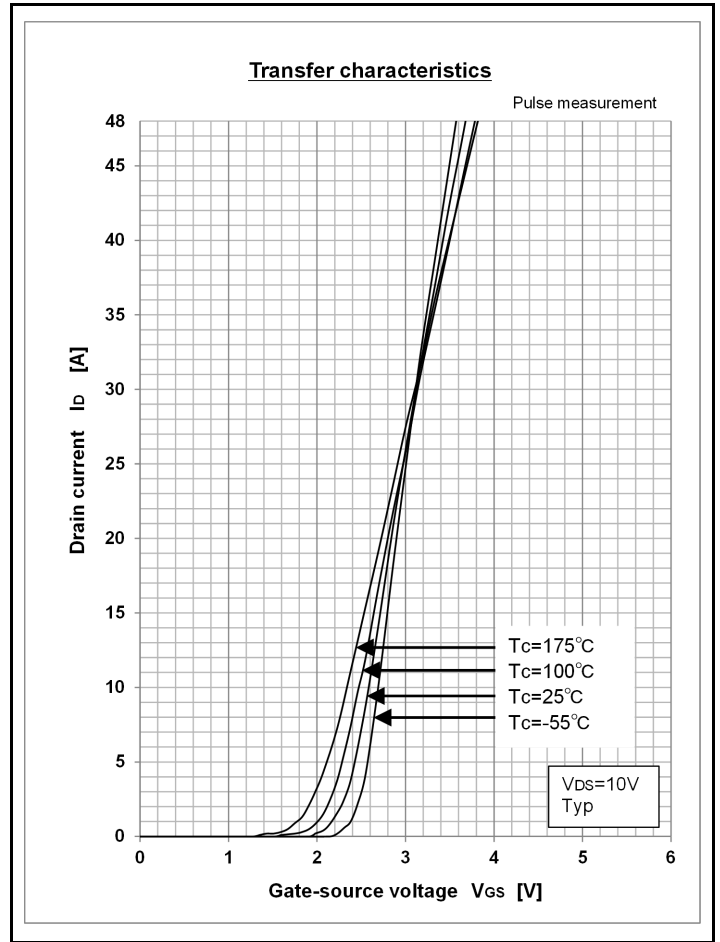
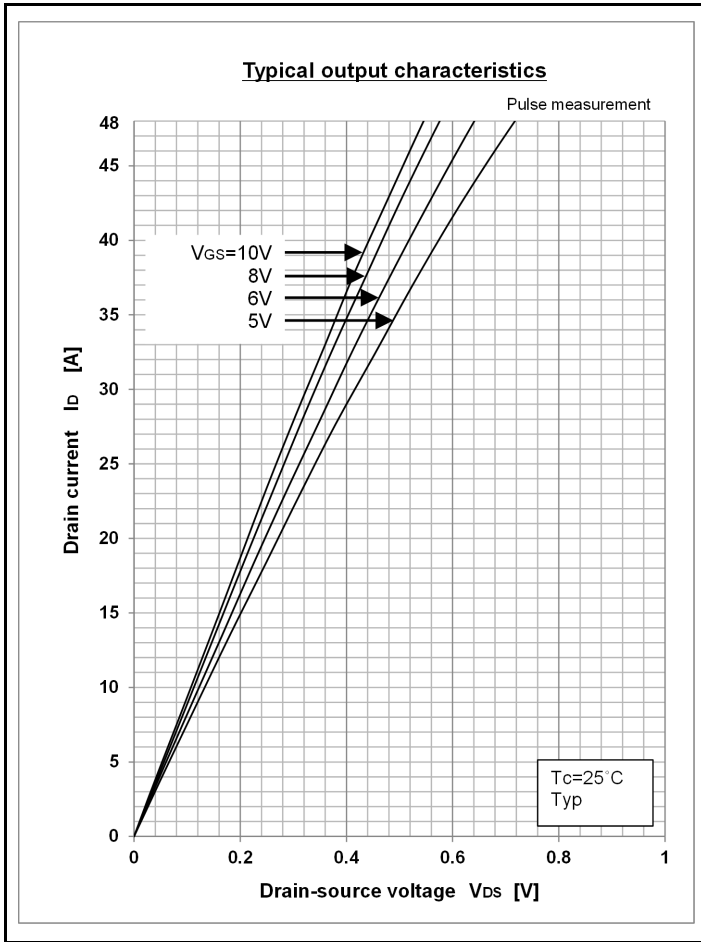
* : See the original Specifications

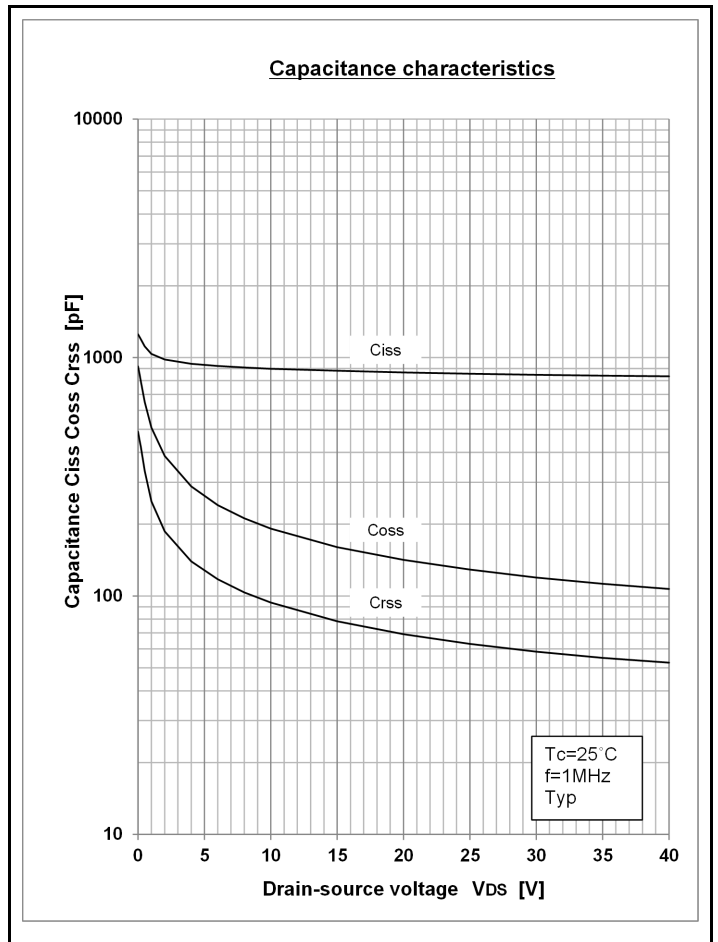
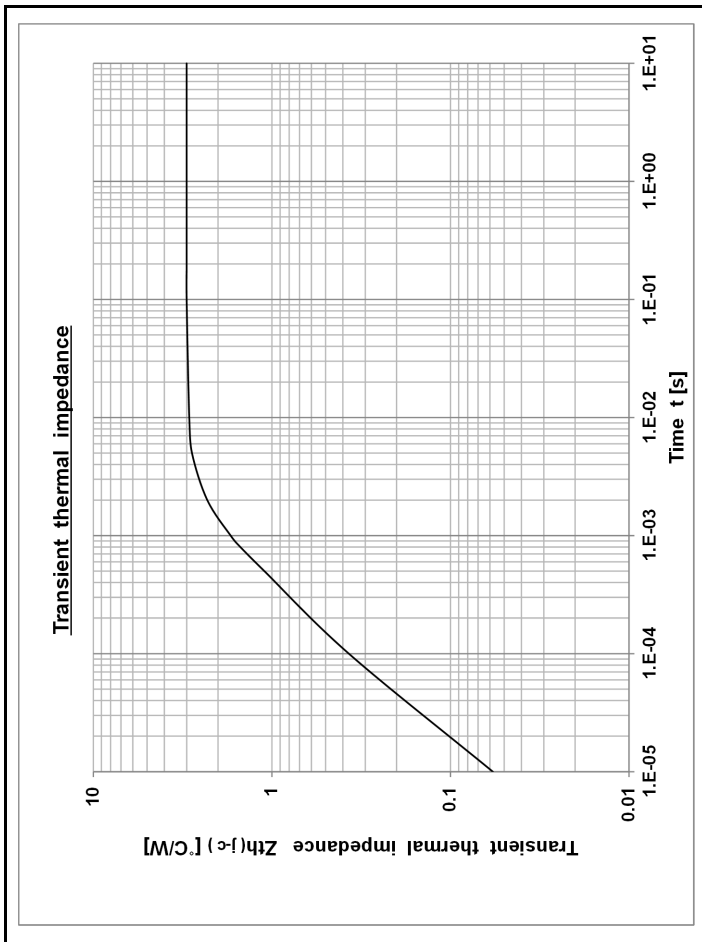
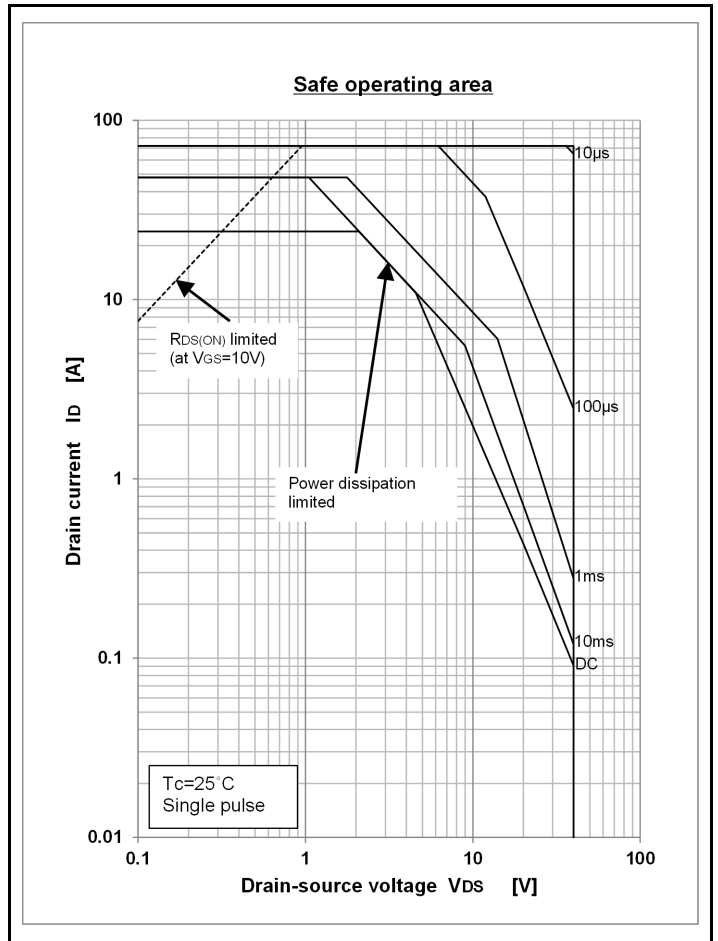
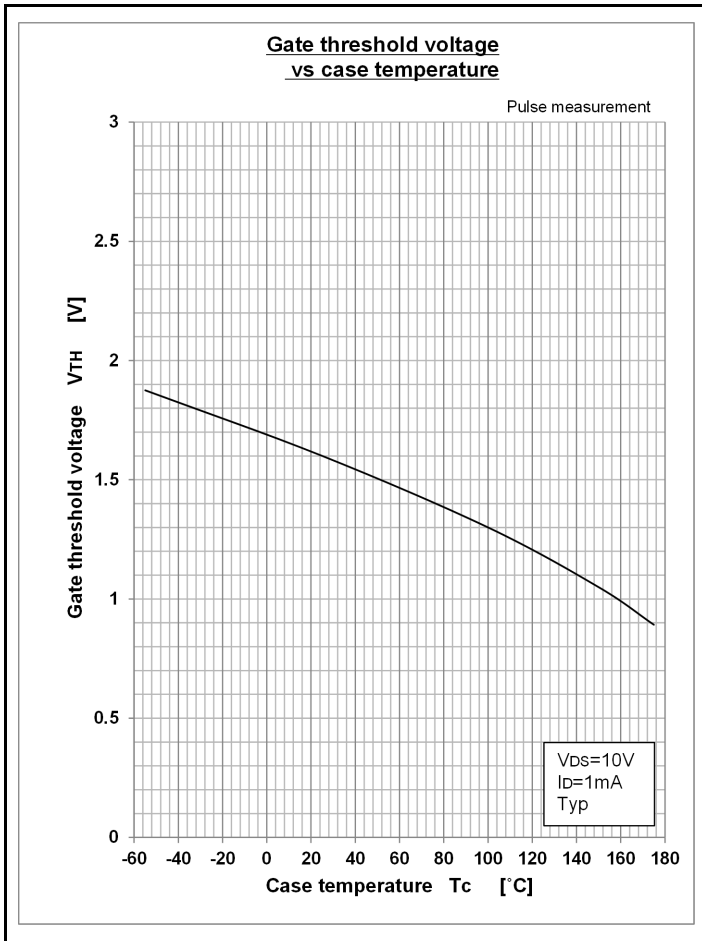
Electrical Characteristics (unless otherwise specified : Tc=25°C)

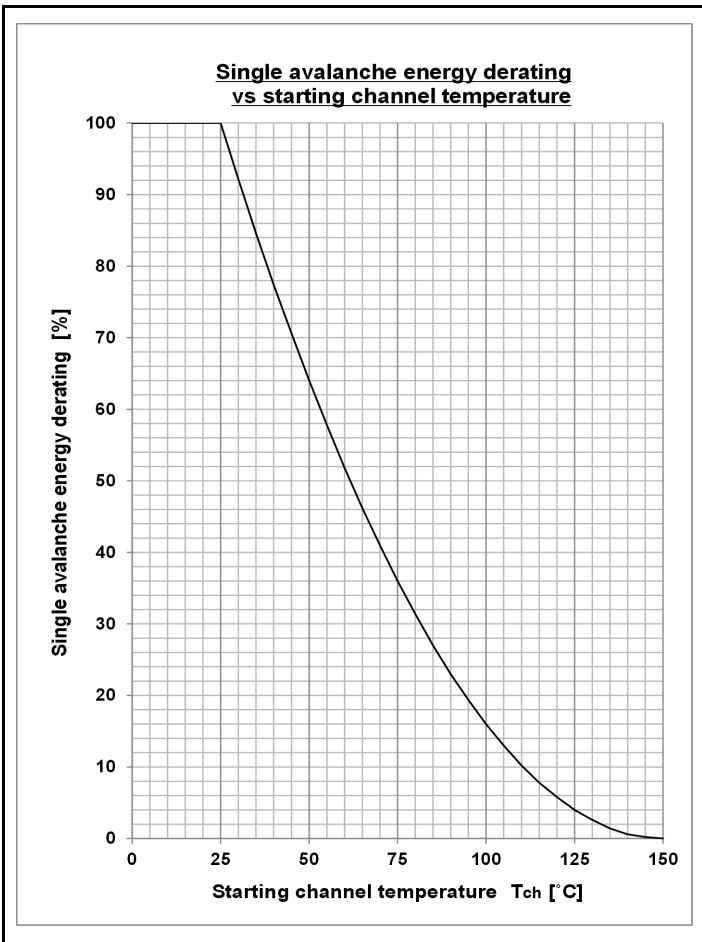
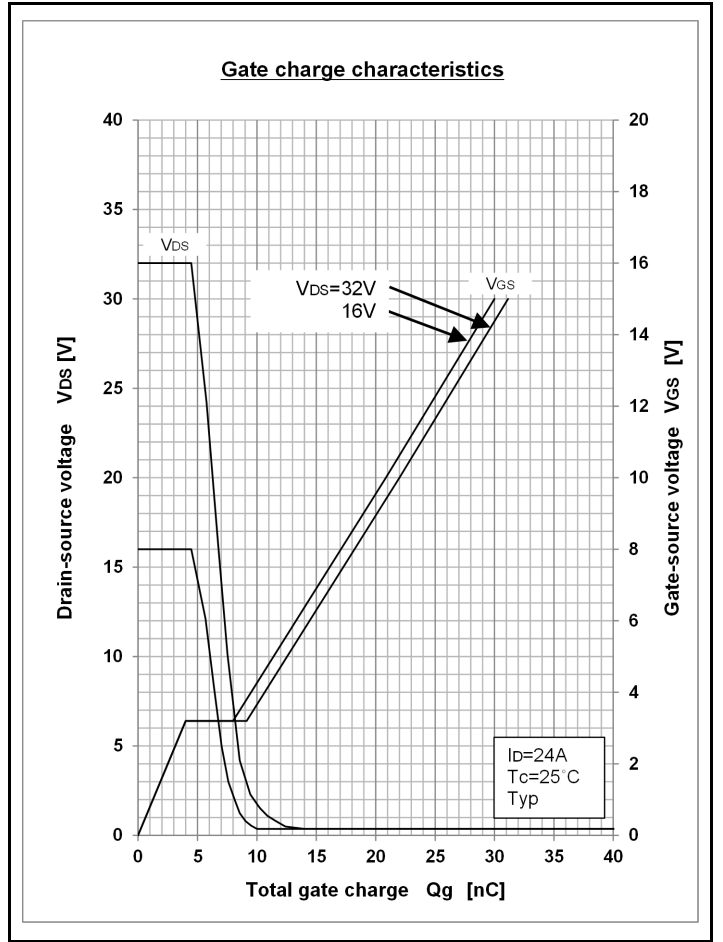
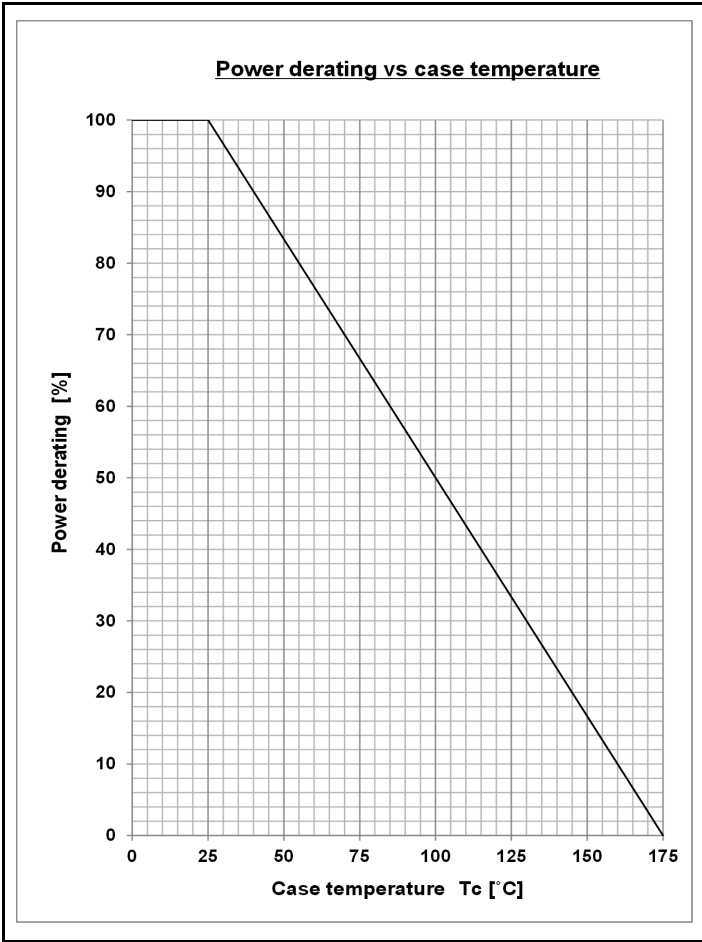
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	40			V
Zero gate voltage drain current	I_{DSS}	VDS=40V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=12A, VDS=10V	6			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=12A, VGS=10V		0.0105	0.0132	Ω
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=10A, VGS=4V		0.0154	0.022	Ω
Gate threshold voltage	V_{th}	ID=1mA, VDS=10V	1.2	1.6	2	V
Source-drain diode forward voltage	V_{SD}	IS=24A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink			3	°C/W
Total gate charge	Q_g	VDD=32V, VGS=10V, ID=24A		22		nC
Gate to source charge	Q_{gs}	VDD=32V, VGS=10V, ID=24A		4.5		nC
Gate to drain charge	Q_{gd}	VDD=32V, VGS=10V, ID=24A		5		nC
Input capacitance	C_{iss}	VDS=25V, VGS=0V, f=1MHz		856		pF
Reverse transfer capacitance	C_{rss}	VDS=25V, VGS=0V, f=1MHz		63		pF
Output capacitance	C_{oss}	VDS=25V, VGS=0V, f=1MHz		129		pF
Turn-on delay time	$t_{d(on)}$	ID=12A, RL=1.67Ω, VDD=20V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		3		ns
Rise time	t_r	ID=12A, RL=1.67Ω, VDD=20V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		7		ns
Turn-off delay time	$t_{d(off)}$	ID=12A, RL=1.67Ω, VDD=20V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		14		ns
Fall time	t_f	ID=12A, RL=1.67Ω, VDD=20V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4.5		ns
Diode reverse recovery time	t_{rr}	IF=24A, VGS=0V, di/dt=100A/μs		32		ns
Diode reverse recovery charge	Q_{rr}	IF=24A, VGS=0V, di/dt=100A/μs		26		nC

* : See the original Specifications

CHARACTERISTIC DIAGRAMS

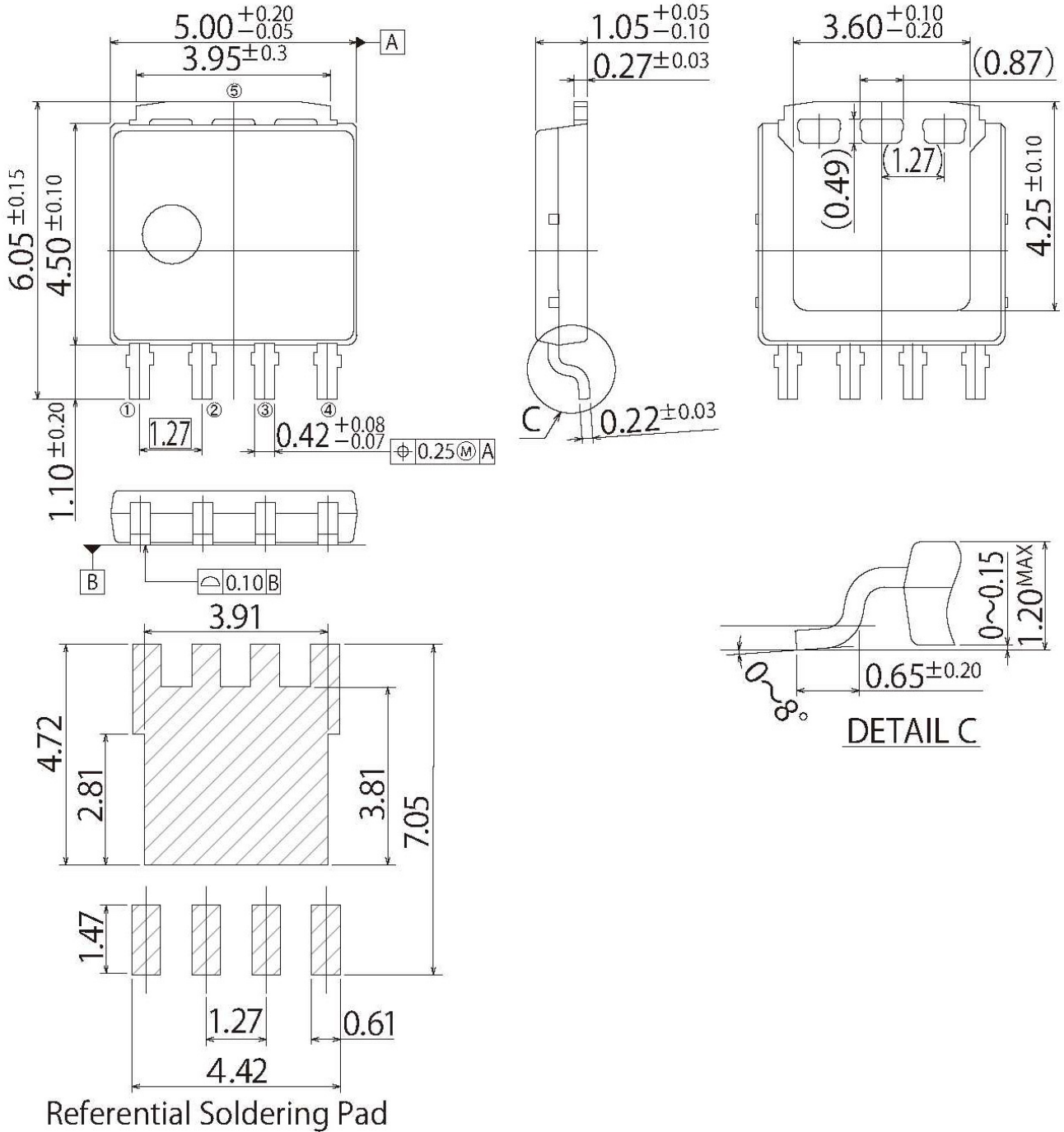






G7

JEDEC Code	MO-235B similar
JEITA Code	-
House Name	LF



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